

- ★ Green Device Available
- ★ Super Low Gate Charge
- ★ Excellent CdV/dt effect decline
- ★ Advanced high cell density Trench technology

Product Summary



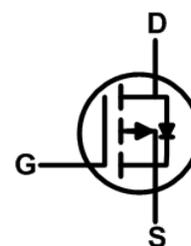
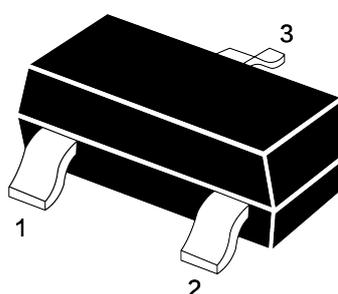
BVDSS	RDSON	ID
-40V	63mΩ	-4 A

Description

The JH2319 is the high cell density trenched P-ch MOSFETs, which provides excellent RDSON and efficiency for most of the small power switching and load switch applications.

The JH2319 meet the RoHS and Green Product requirement with full function reliability approved.

SOT-23-3L Pin Configu



Absolute Maximum Rating ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Units
Drain-Source Voltage		V_{DS}	-40	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_A = 25^{\circ}\text{C}$	I_D	-4	A
Pulsed Drain Current ¹		I_{DM}	-20	A
Power Dissipation	$T_A = 25^{\circ}\text{C}$	P_D	1.2	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 150	$^{\circ}\text{C}$

Thermal Characteristics

Parameter	Symbol	Value	Units
Thermal Resistance from Junction to Ambient ²	$R_{\theta JA}$	104	$^{\circ}\text{C}/\text{W}$

Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Static Characteristics						
Drain-Source Breakdown Voltage	V_{(BR)DSS}	V _{GS} = 0V, I _D = -250μA	-40	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V _{DS} = -40V, V _{GS} = 0V	-	-	-1	μA
Gate-Body Leakage	I_{GSS}	V _{DS} = 0V, V _{GS} = ±20V	-	-	±100	nA
Gate-Threshold Voltage	V_{GS(th)}	V _{DS} = V _{GS} , I _D = -250μA	-1.2	-1.5	-2.5	V
Drain-Source on-Resistance ³	R_{DS(on)}	V _{GS} = -10V, I _D = -5A	-	63	85	mΩ
		V _{GS} = -4.5V, I _D = -4A	-	80	125	
Dynamic Characteristics⁴						
Input Capacitance	C_{iss}	V _{GS} = 0V, V _{DS} = -20V, f=1.0MHz	-	553	-	pF
Output Capacitance	C_{oss}		-	50	-	
Reverse Transfer Capacitance	C_{rss}		-	42	-	
Switching Characteristics⁴						
Total Gate Charge	Q_g	V _{GS} = -10V, V _{DS} = -20V, I _D = -5A	-	11.8	-	nC
Gate-Source Charge	Q_{gs}		-	2.2	-	
Gate-Drain Charge	Q_{gd}		-	3	-	
Turn-on Delay Time	t_{d(on)}	V _{DS} = -20V, V _{GS} = -10V R _L = 2.5Ω, R _G = 3Ω	-	7	-	ns
Rise Time	t_r		-	6.5	-	
Turn-off Delay Time	t_{d(off)}		-	24	-	
Fall Time	t_f		-	7.8	-	
Drain-Source Body Diode Characteristics						
Body Diode voltage ³	V_{DS}	I _S = -5A, V _{GS} =0V	-	-	-1.2	V
Continuous Source Current	I_S		-	-	-4	A

Notes:

1. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C.
2. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper, The value in any given application depends on the user's specific board design.
3. Pulse Test: Pulse width≤300μs, duty cycle≤2%.
4. This value is guaranteed by design hence it is not included in the production test.

Typical Characteristics

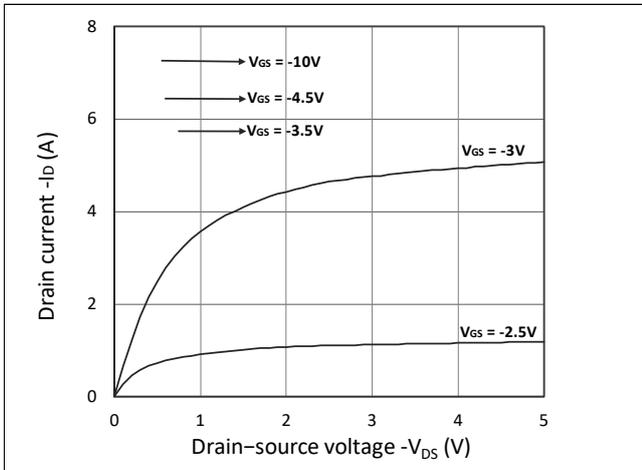


Figure 1. Output Characteristics

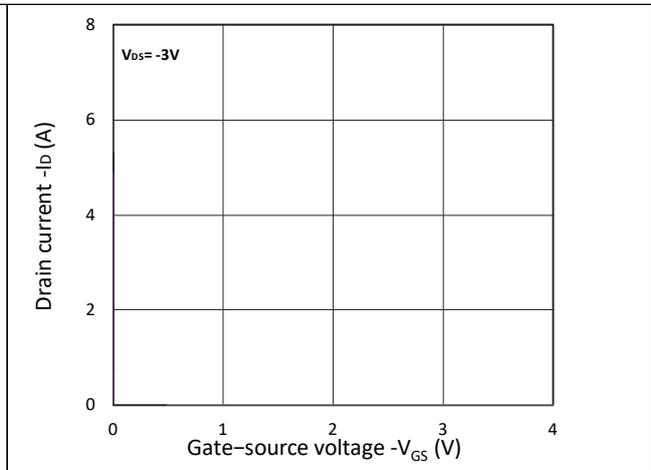


Figure 2. Transfer Characteristics

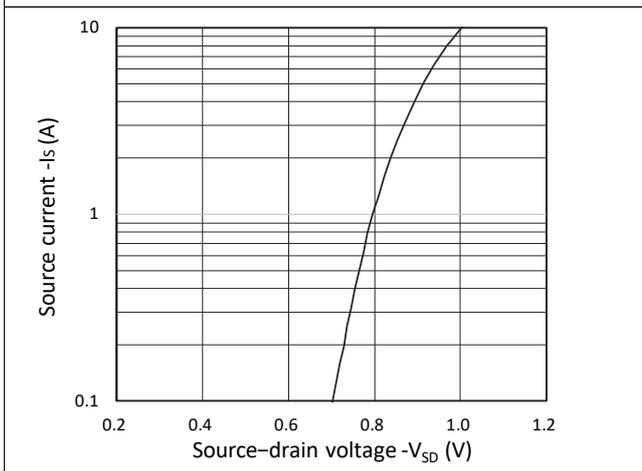


Figure 3. Forward Characteristics of Reverse

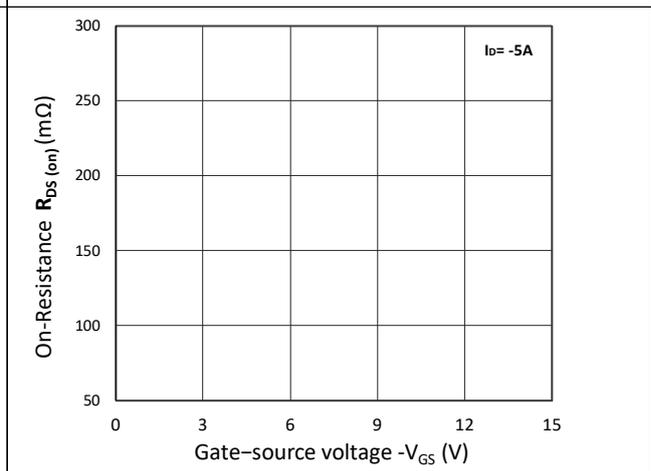


Figure 4. $R_{DS(ON)}$ vs. V_{GS}

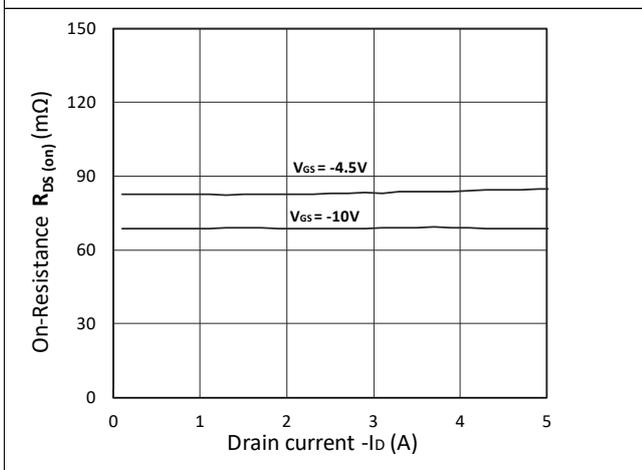


Figure 5. $R_{DS(ON)}$ vs. I_D

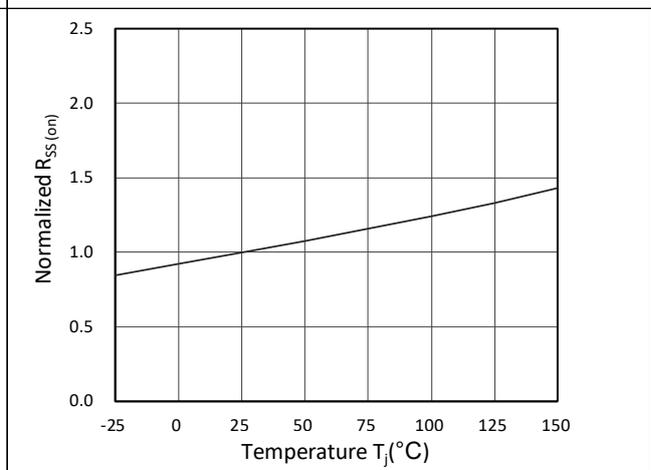


Figure 6. Normalized $R_{DS(ON)}$ vs. Temperature

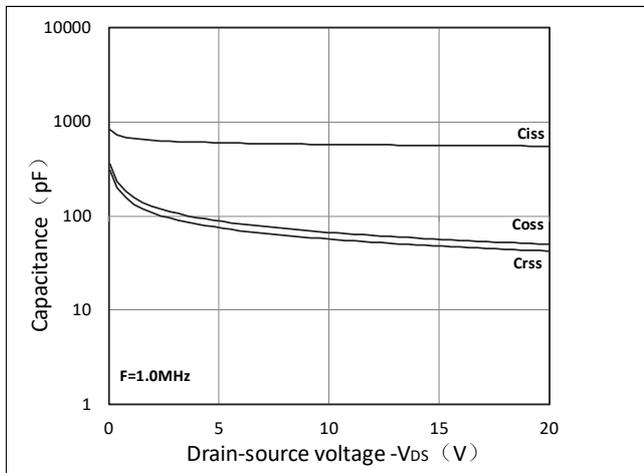


Figure 7. Capacitance Characteristics

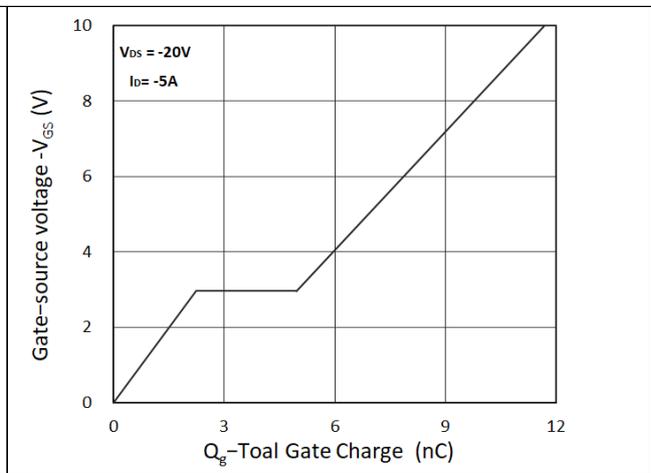
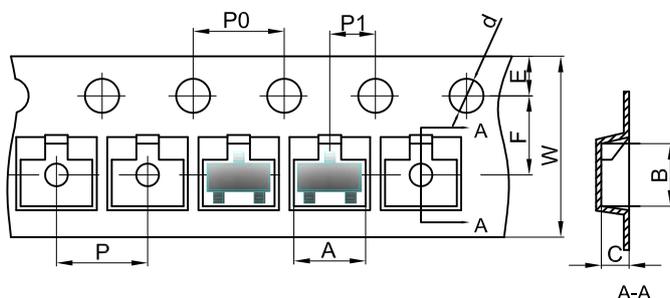


Figure 8. Gate Charge Characteristics

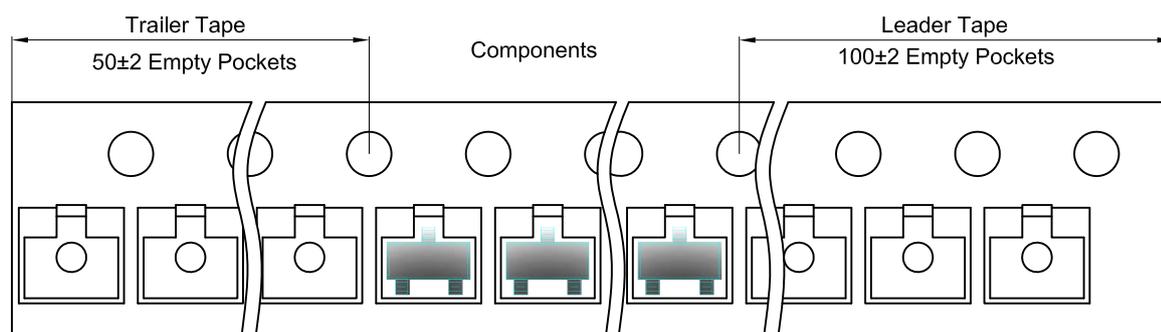
SOT-23-3L Tape and Reel

SOT-23-3L Embossed Carrier Tape

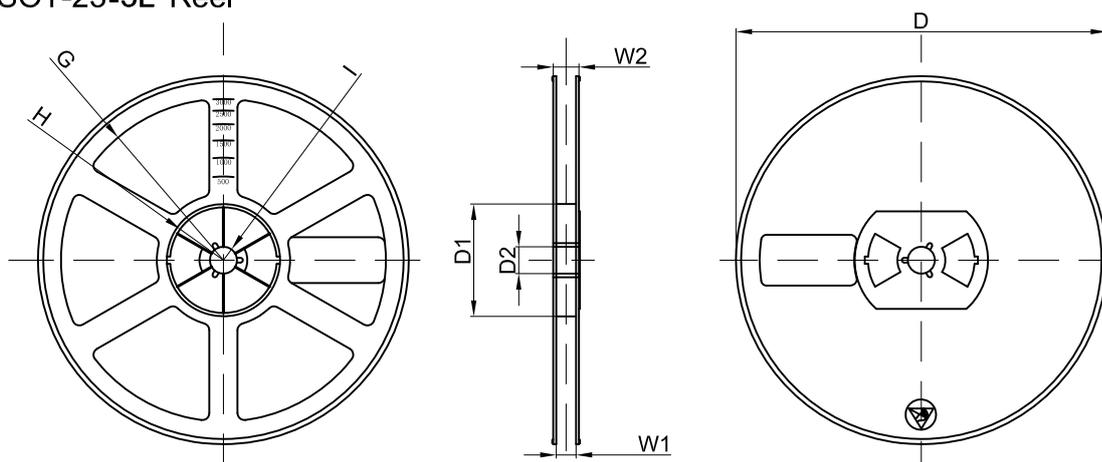


Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-3L Tape Leader and Trailer

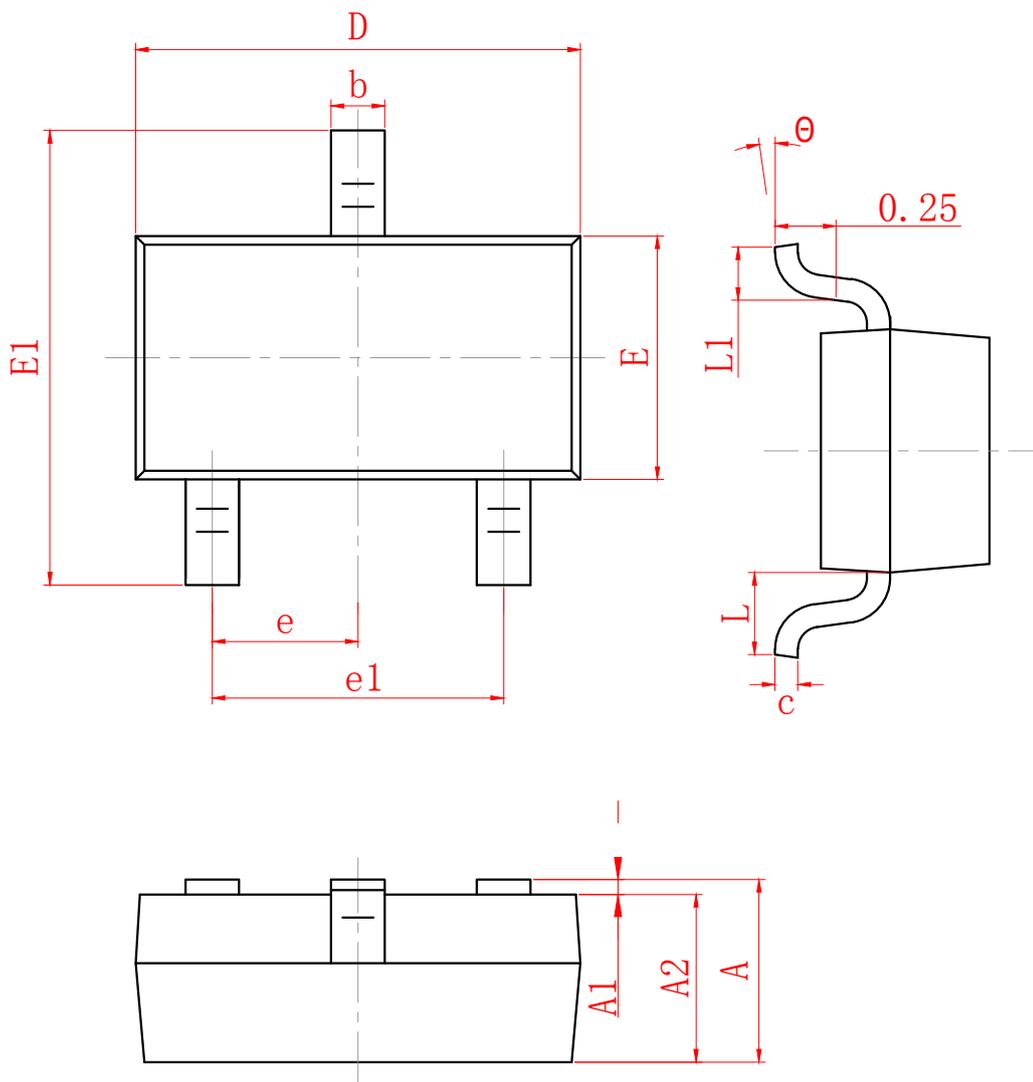


SOT-23-3L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	



SYMBOL	MILLIMETER	
	MIN	MAX
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950 TYP	
e1	1.800	2.000
L	0.550 REF	
L1	0.300	0.500
θ	0°	8°

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